

UNISONIC TECHNOLOGIES CO., LTD

UT03P03MZ

Preliminary

Power MOSFET

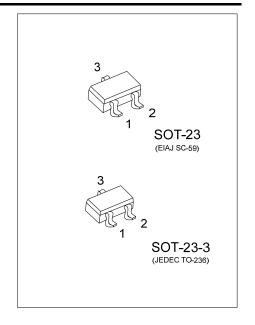
-0.3A, -30V P-CHANNEL POWER MOSFET

■ DESCRIPTION

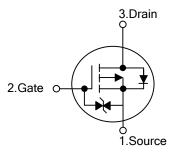
The UTC **UT03P03MZ** is a P-channel enhancement mode power MOSFET with fast switching speed, low on-resistance and favorable stabilization. It can be used in commercial and industrial surface mount applications and suited for low voltage applications such as DC/DC converters.

■ FEATURES

- * $R_{DS(ON)} \le 2.1 \Omega$ @ V_{GS} =-10V, I_{D} =-0.3A $R_{DS(ON)} \le 4.2 \Omega$ @ V_{GS} =-4.5V, I_{D} =-0.15A
- * Low on-resistance
- * Low drive current
- *High speed switching
- * With ESD protection



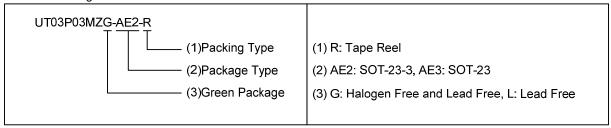
■ SYMBOL



■ ORDERING INFORMATION

Ordering Number		Daalaana	Pin Assignment			D. alain a	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UT03P03MZL-AE2-R	UT03P03MZG-AE2-R	SOT-23-3	G	S	D	Tape Reel	
UT03P03MZL-AE3-R	UT03P03MZG-AE3-R	SOT-23	G	S	D	Tape Reel	

Note: Pin Assignment: G: Gate S: Source D: Drain



MARKING



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■ ABSOLUTE MAXIMUM RATINGS (T_C=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V _{DSS}	-30	V
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current	Continuous	ID	-0.3	Α
Pulsed Drain Current	Pulsed (Note 2)	Ірм	-0.6	Α
Power Dissipation	SOT-23	-	0.2	W
	SOT-23-3	P _D	0.15	W
Junction Temperature		ТJ	+150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

■ THERMAL DATA

PARAMETER		SYMBOL	RATING	UNIT	
Junction to Ambient	SOT-23	0	625 (Note)	°C/W	
	SOT-23-3	ӨЈА	833 (Note)	°C/W	

Note: Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

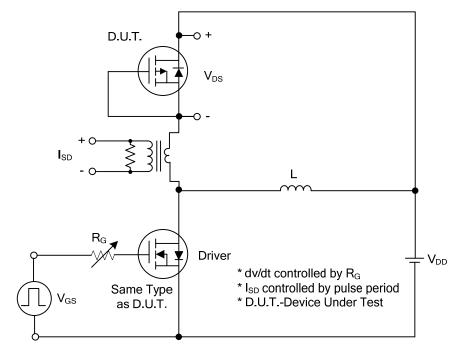
■ ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS N		TYP	MAX	UNIT
OFF CHARACTERISTICS	_			_		_	
Drain-Source Breakdown Voltage		BV_{DSS}	V _{GS} =0 V, I _D =-250µA	-30			V
Drain-Source Leakage Current		I_{DSS}	V_{DS} =-30V, V_{GS} =0V			-1	μΑ
Gate-Source Leakage Current	Forward	1	V _{DS} =0V, V _{GS} =+20V			10	μΑ
	Reverse	I _{GSS}	V _{DS} =0V, V _{GS} =-20V			-10	μΑ
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	V _{DS} =V _{GS} , I _D =-250µA	-1.0		-3.0	V
Otatia Busin Carres On Otata Basintanas	C	V _{GS} =-10V, I _D =-0.3A			2.1	Ω	
Static Drain-Source On-State Resistance		R _{DS(ON)}	V _{GS} =-4.5V, I _D =-0.15A			4.2	Ω
DYNAMIC PARAMETERS							
Input Capacitance		Ciss			19		nF
Output Capacitance		Coss	V _{GS} =0V, V _{DS} =-15V, f=1.0MHz		10		nF
Reverse Transfer Capacitance		Crss			5		nF
SWITCHING PARAMETERS	_						_
Total Gate Charge		Q_{G}	\(\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \		6		nC
Gate to Source Charge		Q _{GS}	V _{DS} =-24V, V _{GS} =-10V, I _D =-0.3A		1		nC
Gate to Drain Charge		Q_{GD}	(Note 1, 2)		1		nC
Turn-ON Delay Time		t _{D(ON)}			1		ns
Rise Time		t _R	V _{DS} =-15V, V _{GS} =-10V, I _D =-0.3A,		18		ns
Turn-OFF Delay Time		t _{D(OFF)}	R _G =3Ω (Note 1, 2)		7		ns
Fall-Time		t _F			18		ns
SOURCE-DRAIN DIODE RATIN	NGS AND C	CHARACTE	RISTICS				
Maximum Continuous Drain-Source Diode		ls				-0.3	Α
Forward Current						-0.0	
Diode Forward Voltage		V_{SD}	Is=-0.3A, V _{GS} =0V			-1.2	V

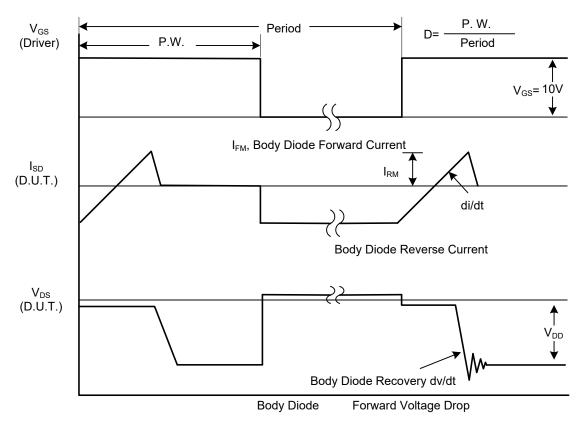
Notes: 1. Pulse Test: Pulse width \leq 300µs, Duty cycle \leq 2%.

2. Essentially independent of operating temperature.

TEST CIRCUITS AND WAVEFORMS

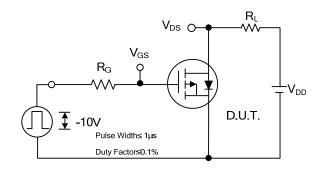


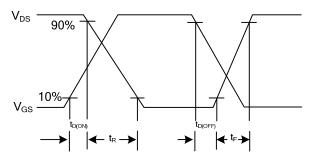
Peak Diode Recovery dv/dt Test Circuit



Peak Diode Recovery dv/dt Waveforms

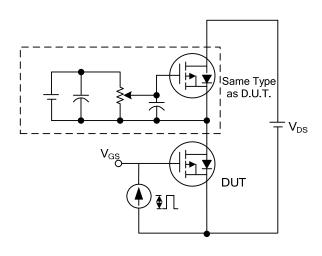
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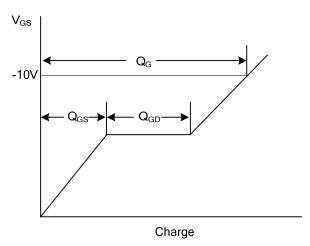




Switching Test Circuit

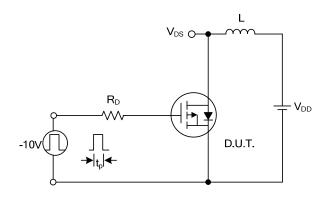
Switching Waveforms

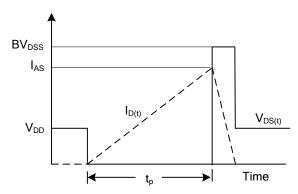




Gate Charge Test Circuit

Gate Charge Waveform





Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms

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